

## MMBT3906

### PNP General Purpose Amplifier

#### Features

- Collector current capability  $I_C = -200 \text{ mA}$
- Collector-emitter voltage  $V_{CEO} = -40 \text{ V}$
- RoHS compliant package

#### Application

- General switching and amplification

#### Mechanical Data

Case outline: SOT-23

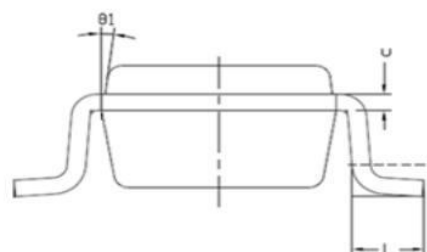
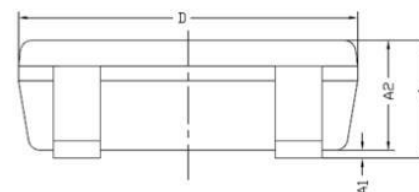
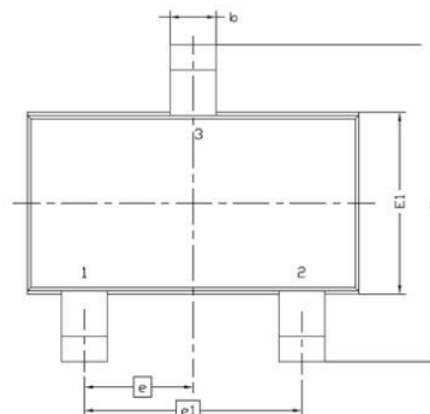
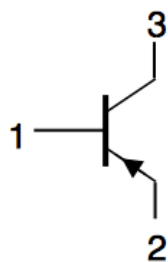
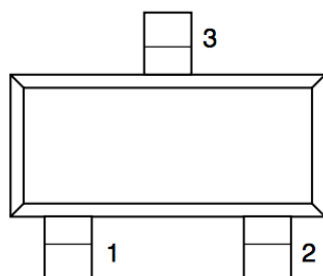
#### Packing & Order Information

3,000/Reel



**RoHS**  
COMPLIANT

Graphic symbol



Symbol	MILLIMETERS	
	MIN	MAX
A	0.8	1.2
A1	0	0.1
A2	0.7	1.1
b	0.3	0.5
c	0.1	0.2
D	2.7	3.1
E	2.6	3
E1	1.4	1.8
e	0.95 BSC	
e1	1.9 BSC	
L	0.3	0.6
θ1	7° NOM	

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#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

##### MAXIMUM RATINGS

Symbol	Characteristic	Rating	Unit
$V_{CBO}$	Collector-Base Voltage	-40	Vdc
$V_{CEO}$	Collector-Emitter Voltage	-40	Vdc
$V_{EBO}$	Emitter-Base Voltage	-6	Vdc
$I_C$	Collector Current -Continuous	-200	mAdc

##### THERMAL CHARACTERISTICS

Symbol	Characteristic	Max	Unit
$P_D$	Total Device Dissipation	225	mW
	FR-5 Board(1)		
	$T_A=25^{\circ}\text{C}$	1.8	mW/ $^{\circ}\text{C}$
	Derate above $25^{\circ}\text{C}$		

##### THERMAL CHARACTERISTICS

Symbol	Characteristic	Rating	Unit
$P_D$	Total Device Dissipation	300	mW
	Alumina Substrate		
	$T_A=25^{\circ}\text{C}$	2.4	mW/ $^{\circ}\text{C}$
	Derate above $25^{\circ}\text{C}$		
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	417	$^{\circ}\text{C}/\text{W}$
$T_J, T_{stg}$	Junction and Storage Temperature	150 $^{\circ}\text{C}$ , -55 to + 150 $^{\circ}\text{C}$	

#### ELECTRICAL CHARACTERISTICS @ $T_A=25^{\circ}\text{C}$ unless otherwise specified

##### OFF CHARACTERISTICS

Symbol	Characteristic	Min	Max	Unit
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage(3) ( $I_C = -1.0\text{mA}$ , $I_B = 0$ )	-40	--	Vdc
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ( $I_C = -10\mu\text{A}$ , $I_E = 0$ )	-40	--	Vdc
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ( $I_E = -10\mu\text{A}$ , $I_C = 0$ )	-6.0	--	Vdc
$I_{BEX}$	Base Cutoff Current ( $V_{CE} = -30\text{V}$ , $V_{EB} = -3.0\text{V}$ )	--	-50	nAdc
$I_{CEX}$	Collector Cutoff Current ( $V_{CE} = -30\text{V}$ , $V_{EB} = -3.0\text{V}$ )	--	-50	nAdc

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#### ON CHARACTERISTICS

Symbol	Characteristic	Min	Max	Unit
h <sub>FE</sub>	DC Current Gain			--
	I <sub>C</sub> = -0.1mA <sub>dc</sub> , V <sub>CE</sub> = -1.0V <sub>dc</sub>	40	--	
	I <sub>C</sub> = -1.0mA <sub>dc</sub> , V <sub>CE</sub> = -1.0V <sub>dc</sub>	70	--	
	I <sub>C</sub> = -10mA <sub>dc</sub> , V <sub>CE</sub> = -1.0V <sub>dc</sub>	100	300	
	I <sub>C</sub> = -50mA <sub>dc</sub> , V <sub>CE</sub> = -1.0V <sub>dc</sub>	60	--	
	I <sub>C</sub> = -100mA <sub>dc</sub> , V <sub>CE</sub> = -1.0V <sub>dc</sub>	30	--	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage (I <sub>C</sub> = -10mA <sub>dc</sub> , V <sub>B</sub> = -1.0 mA <sub>dc</sub> )	--	-0.25	V <sub>dc</sub>
	(I <sub>C</sub> = -50mA <sub>dc</sub> , V <sub>B</sub> = -5.0 mA <sub>dc</sub> )	--	-0.4	

#### ON CHARACTERISTICS

Symbol	Characteristic	Min	Max	Unit
V <sub>CE(sat)</sub>	Base-Emitter Saturation Voltage			
	(I <sub>C</sub> = -10mA <sub>dc</sub> , V <sub>B</sub> = -1.0 mA <sub>dc</sub> )	-0.65	-0.85	V <sub>dc</sub>
	(I <sub>C</sub> = -50mA <sub>dc</sub> , V <sub>B</sub> = -5.0 mA <sub>dc</sub> )	--	-0.95	

#### SMALL-SIGNAL CHARACTERISTICS

Symbol	Characteristic	Min	Max	Unit
f <sub>r</sub>	Current-Gain-Bandwidth Product (I <sub>C</sub> = -10mA <sub>dc</sub> , V <sub>CE</sub> = -20V <sub>dc</sub> , f = 100MHz)	300	--	MHZ
C <sub>obo</sub>	Output Capacitance (V <sub>CB</sub> = -5.0V <sub>dc</sub> , I <sub>E</sub> = 0 , f = 1.0MHz)	--	4.0	pF
C <sub>ibo</sub>	Input Capacitance (V <sub>EB</sub> = -0.5V <sub>dc</sub> , I <sub>C</sub> =0 , f = 1.0MHz)	--	8.0	pF
H <sub>ie</sub>	Input Impedance (V <sub>CE</sub> = -10V <sub>dc</sub> , I <sub>C</sub> = -1.0mA <sub>dc</sub> , f = 1.0KHz)	1.0	10	kΩ
H <sub>re</sub>	Voltage Feedback Ratio (V <sub>CE</sub> = -10V <sub>dc</sub> , I <sub>C</sub> = -1.0mA <sub>dc</sub> , f = 1.0KHz)	0.5	8.0	×10 <sup>-4</sup>
H <sub>fe</sub>	Small-Signal Current Gain (V <sub>CE</sub> = -10V <sub>dc</sub> , I <sub>C</sub> = -1.0mA <sub>dc</sub> , f = 1.0KHz)	100	400	--
H <sub>oe</sub>	Output Admittance (V <sub>CE</sub> = -10V <sub>dc</sub> , I <sub>C</sub> = -1.0mA <sub>dc</sub> , f = 1.0KHz)	1.0	40	μmhos
NF	Noise Figure (V <sub>CE</sub> = -5.0V <sub>dc</sub> , I <sub>C</sub> = -100μA <sub>dc</sub> , R <sub>s</sub> = 1.0kΩ <sub>f</sub> = 1.0KHz)	--	5.0	dB

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#### SMALL-SIGNAL CHARACTERISTICS

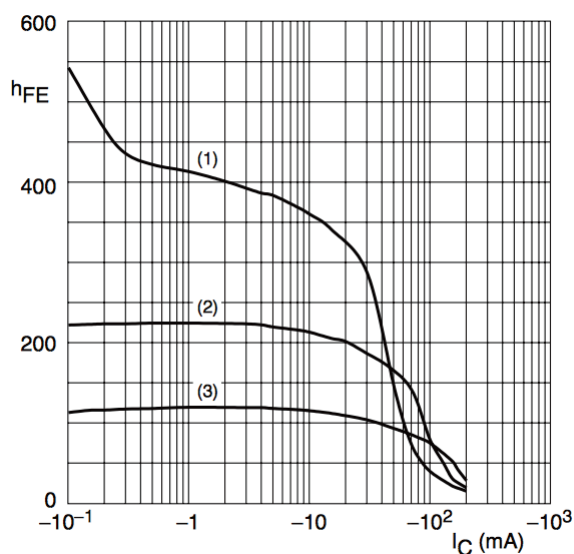
Symbol	Characteristic		Min	Max	Unit
$t_d$	Delay Time	$(V_{CC} = -3.0V_{dc}, V_{BE} = -0.5V_{dc}, I_C = -10mA_{dc}, I_{B1} = -1.0mA_{dc})$	--	35	ns
$t_r$	Rise Time		--	35	ns
$t_s$	Storage Time	$(V_{CC} = -3.0V_{dc}, I_C = -10 mA_{dc}, I_{B1} = I_{B2} = -1.0mA_{dc})$	--	225	ns
$t_f$	Fall Time		--	75	ns

1. FR-5=1.0 × 0.75 × 0.062in.
2. Alumina=0.4 × 0.3 × 0.024in. 99.5% alumina.
3. Pulse Width ≤ 300us,Duty Cycle ≤2.0%
4. Pulse Test : Pulse Width ≤ 300us ; Duty Cycle 2.0%

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#### Characteristics Curve



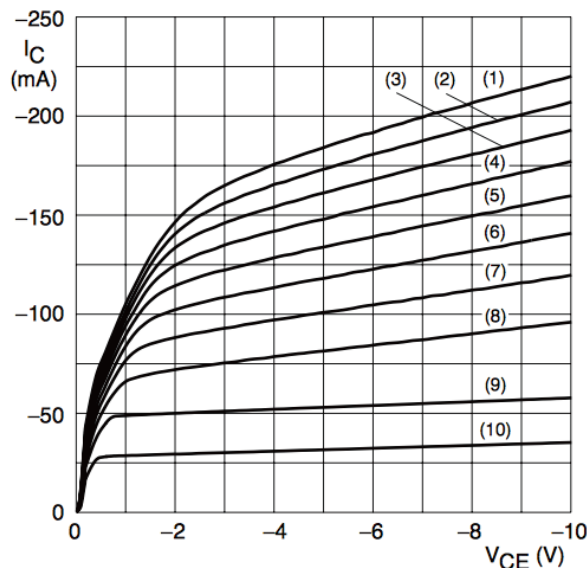
$V_{CE} = -1 \text{ V.}$

(1)  $T_{amb} = 150 \text{ °C.}$

(2)  $T_{amb} = 25 \text{ °C.}$

(3)  $T_{amb} = -55 \text{ °C.}$

FIG.1-DC current gain; typical values



$T_{amb} = 25 \text{ °C.}$

(1)  $I_B = -1.5 \text{ mA.}$

(2)  $I_B = -1.35 \text{ mA.}$

(3)  $I_B = -1.2 \text{ mA.}$

(4)  $I_B = -1.05 \text{ mA.}$

(5)  $I_B = -0.9 \text{ mA.}$

(6)  $I_B = -0.75 \text{ mA.}$

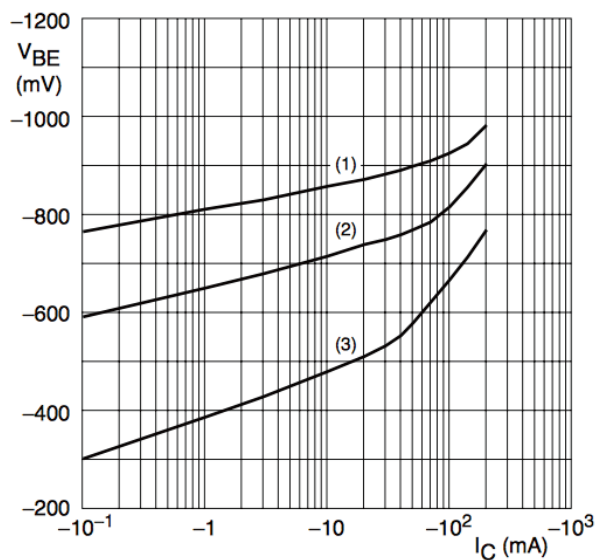
(7)  $I_B = -0.6 \text{ mA.}$

(8)  $I_B = -0.45 \text{ mA.}$

(9)  $I_B = -0.3 \text{ mA.}$

(10)  $I_B = -0.15 \text{ mA.}$

FIG.2-Collector current as a function of collector-emitter voltage.



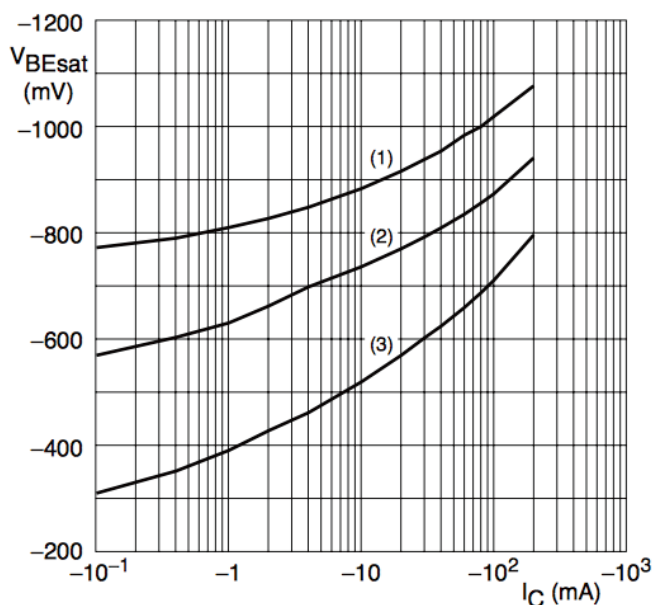
$V_{CE} = -1 \text{ V.}$

(1)  $T_{amb} = -55 \text{ °C.}$

(2)  $T_{amb} = 25 \text{ °C.}$

(3)  $T_{amb} = 150 \text{ °C.}$

FIG.3-Base-emitter voltage as a function of collector current.



$I_C/I_B = 10.$

(1)  $T_{amb} = -55 \text{ °C.}$

(2)  $T_{amb} = 25 \text{ °C.}$

(3)  $T_{amb} = 150 \text{ °C.}$

FIG.4-Base-emitter saturation voltage as a function of collector current.

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